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Evaluation of $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$, Mn^{4+} as a dual-emitter luminescence sensor for cryogenic temperatures†

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The sensitivity of luminescence properties in materials doped with transition metal (TM) ions to changes of temperature makes them particularly promising for thermometric applications. Designing and optimizing such materials requires a deep understanding of their structure, local environment of emission centres, and luminescence processes. In this work, we investigate the potential of Li_2SnO_3 doped with Cr^{3+} and Mn^{4+} as a dual-emitting luminescence temperature sensor. Li_2SnO_3 was chosen as the host material due to it being able to host both Cr^{3+} and Mn^{4+} at Sn octahedral positions. As a result, Mn^{4+} ions exhibit a distinctive ${}^2\text{E} \rightarrow {}^4\text{A}_2$ line emission due to a strong crystal field, and Cr^{3+} ions experience an intermediate crystal field strength resulting in both, ${}^2\text{E} \rightarrow {}^4\text{A}_2$ and ${}^4\text{T}_2 \rightarrow {}^4\text{A}_2$ emissions. Through thorough examination, using powder X-ray diffraction (XRD), electron paramagnetic resonance (EPR) and photoluminescence techniques we identified two distinct types of $[\text{SnO}_6]$ octahedral centers that correspond to two types of slightly different Cr^{3+} and Mn^{4+} emission centers in the Li_2SnO_3 structure. The high sensitivity of the decay time constant for the ${}^2\text{E} \rightarrow {}^4\text{A}_2$ emission of $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} to temperature changes (2.0%/K at 190 K and 5.8%/K at 220 K for Cr^{3+} and Mn^{4+} , respectively) positions the material as an attractive non-contact temperature sensor. Furthermore, application of such a dual-emitter luminescence material as a temperature sensor expands its sensitivity across a broader temperature range and offers the additional advantage of cross-checking measurements compared to materials solely doped with Cr^{3+} or Mn^{4+} .

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Introduction

The electronic configuration of excited states of transition metal (TM) ions with an unfilled 3d shell provides the basis for a unified methodology of interpreting their optical properties within the framework of crystal field theory.^{1,2} This method has been successfully applied towards understanding the nature of the luminescence of Cr^{3+} and Mn^{4+} in different hosts.^{3–8} These ions are typically stabilized in octahedral or distorted octahedral environments, coordinated by six oxygen ions, where the energy structure of 3d states and their dependence

on crystal field strength are well explained by the classical Tanabe–Sugano diagram.^{1,2,7,8} The diagram shows that the energy of most multiplets except ${}^2\text{T}_1$ and ${}^2\text{E}_g$ are strongly dependent on the crystal field strength, which has a decisive impact on luminescence. Mn^{4+} ions doped in various hosts always experience a strong crystal field which gives rise to emission lines from ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions, aided by lattice vibrations.⁵ In contrast, the effect of the surrounding crystal field on Cr^{3+} ions can vary from weak to strong as established through relevant luminescence spectra. Specifically, a broad emission band due to ${}^4\text{T}_2 \rightarrow {}^4\text{A}_2$ transitions and sharp ${}^2\text{E} \rightarrow {}^4\text{A}_2$ lines are simultaneously observed in intermediate crystal fields, while in weak crystal fields the line emission disappears.⁸ This dependence of the emission properties of Cr^{3+} and Mn^{4+} on the strength of the local crystal field enables customization and fine-tuning of the emission characteristics for specific applications.

In this regard, of particular interest is the case when both Cr^{3+} and Mn^{4+} can occupy the same crystallographic position. This may occur in the same host despite of the different valence states of the ions. In such a case the needs to compensate a local charge disparity may create additional perturbations of the crystal field surrounding the impurity, resulting in changes

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of the emission properties. To date only characteristic sharp emission peaks due to spin-forbidden transitions ${}^2E \rightarrow {}^4A_2$ of Cr^{3+} and Mn^{4+} have been reported in several hosts, indicating that both ions are experiencing a strong crystal field effect.^{9–13} It should be noted that such materials with two types of emission centers are particularly interesting for application as multimodal luminescence sensors of temperature.¹⁴ The dual-emitter sensor allows to extend the temperature range of operation and improves the reliability of the technique. It would be interesting therefore to investigate a material where in addition to the spin-forbidden transitions of Mn^{4+} and Cr^{3+} the spin-allowed transitions ${}^4T_2 \rightarrow {}^4A_2$, yielding broadband emission, can also occur. Due to the coexistence of two radiative channels, the luminescence characteristics of such a material may exhibit enhanced sensitivity to changes of temperature that can be exploited for temperature monitoring.

To test this idea we turned our attention to Li_2SnO_3 , a material currently being investigated for its potential as an electrode in lithium batteries^{15–18} and light emitting devices (LED).¹⁹ Li_2SnO_3 has a honeycomb layered monoclinic structure that contains octahedral sites SnO_6 which are suitable for accommodating Mn^{4+} and Cr^{3+} ions with smaller ionic radius ($r = 0.54$ and 0.61 Å, respectively) in place of the larger Sn^{4+} ion ($r = 0.69$ Å). Previous research has shown that Li_2SnO_3 doped with Mn^{4+} exhibits strong red luminescence originating from ${}^2E \rightarrow {}^4A_2$ transitions.^{20,21} However, to the best of our knowledge no studies have been conducted on Cr-doped Li_2SnO_3 . We successfully synthesized the material using a hydrothermal method²² and preliminary examinations have indicated that Cr^{3+} ions occupy the octahedrally-coordinated Sn^{4+} sites in the Li_2SnO_3 host, experiencing a crystal field of intermediate strength ($Dq/B = 2.48$). This field is responsible for the characteristic room temperature luminescence of Cr^{3+} *i.e.* a broad luminescence band spanning the range from 650 to 850 nm with a narrow and sharp emission line at 700 nm. These originate from spin-allowed ${}^4T_2 \rightarrow {}^4A_2$ and spin-forbidden ${}^2E \rightarrow {}^4A_2$ transitions of the Cr^{3+} ion, respectively. In this study we conducted a detailed characterization of Li_2SnO_3 co-doped with Cr^{3+} and Mn^{4+} in the temperature range from 4 to 300 K, aiming to establish the potential of this dual-emitter phosphor for application as non-contact luminescence sensor of temperature.

Experimental methods

The $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} nanocrystalline phosphor was synthesized as described in ref. 22. In particular, the material studied in the present work has been calcined at 1200 °C. The photoluminescence (PL) and the photoluminescence excitation (PLE) spectra were measured using a Horiba/Jobin-Yvon Fluorolog-3 spectrofluorometer with a 450 W continuous spectrum xenon lamp for excitation. The emission was detected by a Hamamatsu R928P photomultiplier operating in a photon counting mode. The PL spectra were corrected for the spectral response of the used system. The luminescence decay kinetics were

measured using the same Fluorolog-3 spectrofluorometer with the excitation light modulated by a mechanical chopper. The spectroscopic measurements in the temperature range of 4.2–330 K were carried out in a Janis continuous-flow liquid helium cryostat using a Lake Shore 331 temperature controller. The studies in the temperature range of 300–600 K were done using a Linkam THMS600 temperature stage.

Electron paramagnetic resonance (EPR) spectra were recorded at a magnetic induction in the range of $B = 10\text{--}1400$ mT on a conventional X-band Bruker ELEXSYS E 500 CW-spectrometer, operating at 9.5 GHz with 100 kHz magnetic induction modulation and microwave power of $P = 2.002$ mW. The temperature dependence of the EPR spectrum was analysed using a nitrogen-flow cryostat (Oxford Instruments ESP) in the nitrogen temperature range. The position of the EPR line is determined by the formula $g_{\text{eff}} = 71\,44\,773\,f_{\text{ez}}(\text{GHz})/B_{\text{rez}}(\text{mT})$, where f_{ez} is the microwave frequency and B_{rez} is the position of the resonance line in the magnetic induction. The EPR/NMR program was used to find local symmetry and Spin-Hamiltonian (SH) parameters of the chromium ions.²³ The optimization and normalization of the above parameters was performed using a root-mean-square deviation method.

Results and discussion

Crystal structure

The crystal structure of Li_2SnO_3 doped with Cr^{3+} was studied recently by X-ray powder diffraction and application of full profile Rietveld refinement. Comprehensive details of the refinement procedure along with a complete set of structural data including unit cell dimension, coordinates, and displacement parameters of atoms can be found in ref. 22. The Li_2SnO_3 structure belonging to space group $C2/c$, $Z = 4$ can be visualised as stacked slabs comprising interconnected $[\text{SnO}_6]$ and $[\text{LiO}_6]$ octahedra in a 2:1 ratio. These are interleaved with layers consisting of Li^+ ions (see Fig. 1). A distinctive feature of

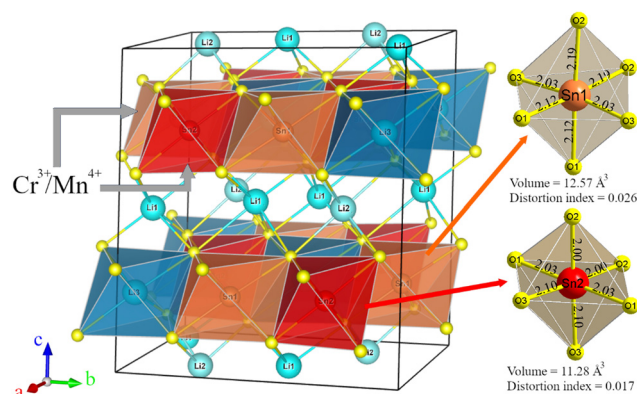


Fig. 1 Representation of Li_2SnO_3 structure as stacked slabs composed of interconnected $[\text{SnO}_6]$ and $[\text{LiO}_6]$ octahedra separated by layers of Li^+ ions. The drawing shows the shortest Li–O and Sn–O interatomic distances. The right panel shows an enlarged view of two structurally nonequivalent octahedral sites of Sn atoms (Sn1 and Sn2), both of which are suitable for the incorporation of Cr^{3+} and Mn^{4+} ions.



the Li_2SnO_3 host structure is the presence of three different octahedral positions of Li^+ ions, located at the 4d, 4e and 8f Wyckoff sites. Furthermore, the structure boasts two non-equivalent four-fold 4e sites, which are occupied by Sn atoms in an octahedral oxygen environment. The octahedral coordination of Sn^{4+} ions in both sites provides a conducive environment for accommodating Cr^{3+} and Mn^{4+} cations.

An examination of the nearest interatomic distances in the $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$ structure, calculated from the atomic coordinates reported in ref. 22, reveals a difference in the configuration of $[\text{SnO}_6]$ octahedra around Sn1 and Sn2 atoms. Specifically, the distribution of the six nearest Sn–O distances inside $[\text{Sn1O}_6]$ and $[\text{Sn2O}_6]$ polyhedra (as listed in Table 1) indicates that the $[\text{Sn1O}_6]$ octahedron with a volume of 12.57 \AA^3 exhibits significantly greater distortion compared to the $[\text{Sn2O}_6]$ octahedron which has a volume of 11.28 \AA^3 (see Fig. 1). Given that dopant ions can incorporate into both of these Sn sites, it is anticipated that there will be two different types of Cr^{3+} and Mn^{4+} centres in the Cr- and Mn-doped Li_2SnO_3 materials. It is worth noting that this peculiarity of the host lattice, namely the existence of two different octahedral Sn sites was not identified in recent publications that studied luminescence properties of $\text{Li}_2\text{SnO}_3:\text{Mn}^{4+}$ phosphors.^{20,21}

Electron paramagnetic resonance studies

EPR allows detection of even small amounts of paramagnetic ions within the studied materials. It aids in discerning key structural properties such as the local symmetry of paramagnetic ions and their interactions. In the case of Li_2SnO_3 doped with Cr^{3+} ions and Mn^{4+} ions, we expect to observe a distinct EPR signal from these dopants. Cr^{3+} ions are paramagnetic ions with an electron configuration of $3d^3$ and an electron spin $S = 3/2$. Similarly, Mn^{4+} ions are paramagnetic ions with an electron configuration of $3d^3$ and electron spin $S = 3/2$. Additionally, for Mn^{4+} ions, we expect an EPR signal arising from the ^{55}Mn isotope (100% abundance) possessing a nuclear spin $S = 5/2$. It is worth noting that the position of the signal is strongly influenced by the local environment of the paramagnetic ions. This feature enables us to ascertain the local symmetry of these dopants. Fig. S1 (ESI[†]) showcases the EPR spectra for the $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$, Mn^{4+} recorded at temperatures $T = 80 \text{ K}$ and $T = 300 \text{ K}$.

The EPR spectra recorded at room temperature exhibit three distinct lines emerging from two magnetic centres. Specifically, the EPR line with $g_{\text{eff}} = 1.999$ can be attributed to the Mn^{4+} ion while the lines with $g_{\text{eff}} = 3.649$ and $g_{\text{eff}} = 1.38$ are characteristic of Cr^{3+} ions within an octahedral environment; notably these two EPR lines corresponds to a single Cr^{3+} centre,^{24,25} As temperature drops, the components of the EPR lines originating from Cr^{3+} ions become more discernible along with the hyperfine interactions of Mn^{4+} ions. To delve further into ion symmetry, we selected the lowest temperature of $T = 80 \text{ K}$ as this provides a clearer understanding of the structural arrangement of the ions in question.

The spin Hamiltonian (SH) parameters for ions with spin $S = 3/2$ were determined using the EPR/NMR programme through the following system of equations:

$$\begin{aligned} H(\text{Cr}^{3+}) &= H_{\text{Zeeman}} + H_{\text{ZFS}} \\ H(\text{Mn}^{4+}) &= H_{\text{Zeeman}} + H_{\text{ZFS}} + H_{\text{HF}} \\ H_{\text{Zeeman}} &= \mu_B B \cdot g \cdot S \\ H_{\text{ZFS}} &= +D \left(S_z^2 - \frac{1}{3} S(S+1) \right) + E(S_x^2 + S_y^2) \\ H_{\text{HF}} &= S \cdot A \cdot I \end{aligned} \quad (1)$$

where μ_B – Bohr magneton, B – magnetic induction, g – spectroscopic splitting factor, S – electron spin, D – axial and E – rhombic distortions of octahedral, A – hyperfine interactions matrix, and I – nuclear spin. The spin Hamiltonian for Cr^{3+} ions possessing a spin $S = 3/2$ comprises a Zeeman term and a zero-field splitting term. In contrast, the spin Hamiltonian for Mn^{4+} ions with spin $S = 3/2$ and $I = 5/2$ consists of a Zeeman term, a zero-field splitting term and hyperfine interactions. Non-zero values of these parameters offer insight into the symmetry of the paramagnetic centre.

For single Cr^{3+} ions the following values were calculated: $g_x = g_y = 1.998(2)$, $g_z = 1.997(2)$, and $D = 0.252(5) \text{ cm}^{-1}$ ($E = 0$). These parameters suggest an axially symmetric site for the Cr^{3+} ions with insignificant distortions of an octahedra. Similarly, for single Mn^{4+} ions the values are: $g_x = g_y = 1.985(3)$, $g_z = 1.980(3)$, $D = 0.006(1) \text{ cm}^{-1}$, $E = 0$, $A_x = A_y = 0.0030(2) \text{ cm}^{-1}$, $A_z = 0.0029(2) \text{ cm}^{-1}$. These parameters affirm an axially symmetric site for the Mn^{4+} ions. The spin Hamiltonian parameters

Table 1 The shortest intra-octahedral distances in the $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$ structure, with corresponding standard deviations given in parentheses. The average distances within different types of $[\text{LiO}_6]$ and $[\text{SnO}_6]$ octahedra are provided for reference

Polyhedron, atoms	Distances in Å	Polyhedron, atoms	Distances in Å	Polyhedron, atoms	Distances in Å
$[\text{Li1O}_6]$		$[\text{Li2O}_6]$		$[\text{Sn1O}_6]$	
Li1–O3	2.02(5)	Li2–O3	$2 \times 2.02(2)$	Sn1–O3	$2 \times 2.04(2)$
Li1–O1	2.17(5)	Li2–O2	$2 \times 2.16(2)$	Sn1–O1	$2 \times 2.12(2)$
Li1–O3	2.25(5)	Li2–O1	$2 \times 2.28(2)$	Sn1–O2	$2 \times 2.19(2)$
Li1–O2	2.32(5)	Li2–O _{ave}	2.15	Sn1–O _{ave}	2.12
Li1–O2	2.32(5)	$[\text{Li3O}_6]$		$[\text{Sn2O}_6]$	
Li1–O1	2.47(5)	Li3–O2	$2 \times 2.06(2)$	Sn2–O2	$2 \times 2.00(2)$
Li1–O _{ave}	2.25	Li3–O1	$2 \times 2.19(2)$	Sn2–O1	$2 \times 2.03(2)$
		Li3–O3	$2 \times 2.19(2)$	Sn2–O3	$2 \times 2.10(2)$
		Li3–O _{ave}	2.15	Sn2–O _{ave}	2.04



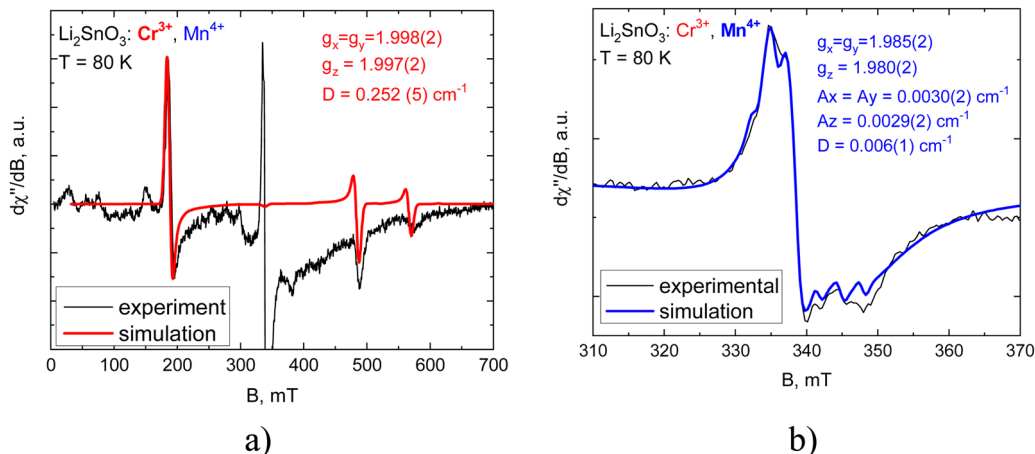


Fig. 2 EPR spectrum of a $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}, \text{Mn}^{4+}$ at temperature $T = 80$ K. The red (a) and blue (b) curves are graphical representations of the resulting SH parameter fits for Cr^{3+} and Mn^{4+} ions, respectively.

were obtained from the best fit of the experimental EPR spectra to the simulated spectra generated using the spin Hamiltonian. Fig. 2(a) and (b) illustrate the experimental spectra and simulated spectra, derived from the above equations and SH parameters.

It is worth noting that at temperatures below $T < 120$ K the signal at $g_{\text{eff}} \sim 3.6$ apparently consists of two EPR lines (inset of Fig. S1, ESI †) of the same intensity. This may indicate that the signal from Cr^{3+} ions originates from two Cr^{3+} centres ($\text{Cr}^{3+} \rightarrow [\text{Sn1O}_6]$ and $[\text{Sn2O}_6]$) with different distortions. EPR studies do not confirm the presence of two different Mn^{4+} centres, but it should be borne in mind that the EPR signal from Mn^{4+} ions consists of many lines originating from fine and hyperfine interactions, meaning that two Mn^{4+} ions with the same symmetry but different distortion cannot be distinguished.

Effect of temperature on the luminescence properties

Previous studies of Li_2SnO_3 doped with Cr^{3+} or $\text{Mn}^{4+19-22}$ provide some insight into the expected emission properties of

this material when co-doped with both ions. Given that the concentration of the impurity ions is maintained at low level ($< 0.1\%$) and there is no spectral overlap between the emission and excitation spectra of different impurities, no energy transfer is expected between the two emitters. Consequently, the luminescence of $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}, \text{Mn}^{4+}$ represents a superposition of emissions from individual ions resulting in a combined spectrum as depicted in Fig. 3.

The configuration coordinate model offers an innate way towards understanding the emission properties of Cr^{3+} and Mn^{4+} ions (see Fig. 4). The vertical blue arrows indicate excitation transitions that promote electrons from the ground state to the $^4\text{T}_{1g}$ and $^4\text{T}_{2g}$ states *via* parity-allowed transitions. The luminescence excitation bands due to these transitions are clearly seen in the luminescence excitation spectra displayed in Fig. 3(b). Subsequently, the electrons promptly relax along the parabola to $^2\text{E}_g$ and $^4\text{T}_{2g}$ states. At this stage the splitting of the subsequent relaxation pathway becomes apparent.

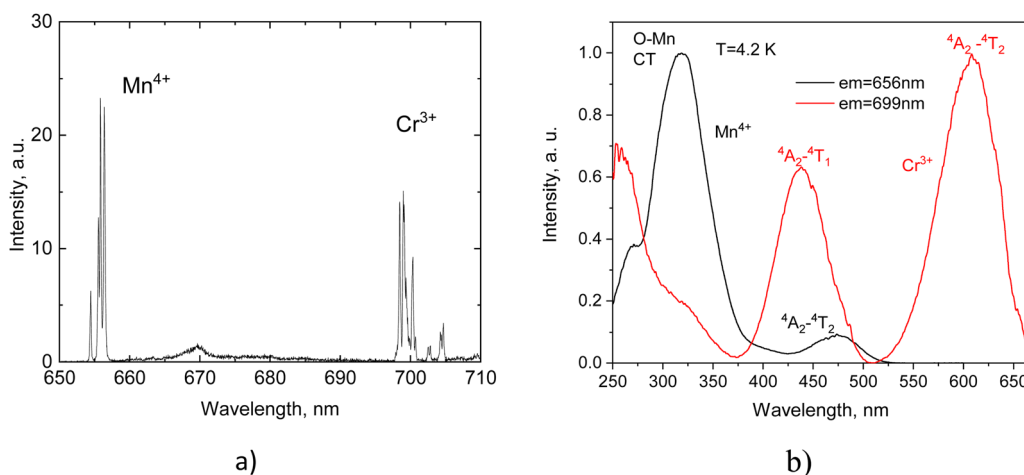


Fig. 3 Luminescence spectrum of $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}, \text{Mn}^{4+}$ measured at 480 nm excitation ($T = 40$ K, (a) and excitation spectra monitored at Cr^{3+} and Mn^{4+} emission peaks at $T = 4.2$ K, (b).



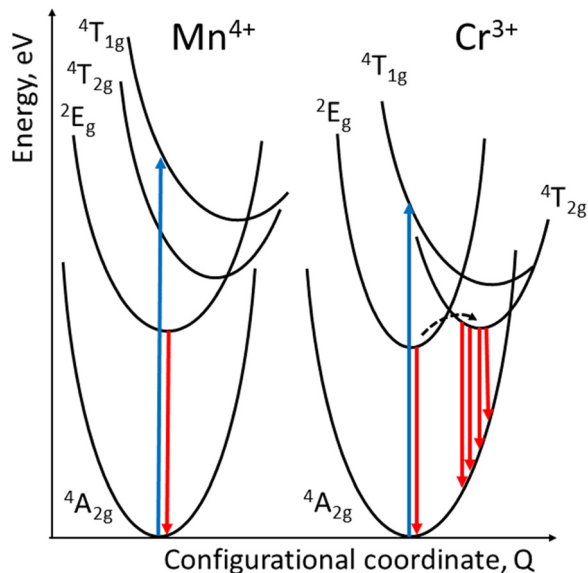


Fig. 4 Energy diagram of Mn^{4+} and Cr^{3+} ions showing excitation (blue), emission (red) and thermally activated (black dotted) transitions.

The strong crystal field experienced by Mn ions shifts the ${}^4\text{T}_{2g}$ states above the ${}^2\text{E}_g$ levels, leaving only one channel for radiative recombination through the spin-forbidden transitions ${}^2\text{E} \rightarrow {}^4\text{A}_2$, giving rise to the sharp emission lines (red arrow). In contrast, the weaker crystal field experienced by Cr^{3+} places the ${}^4\text{T}_{2g}$ states at lower energy, thus opening an additional channel for the radiative recombination through the spin-allowed ${}^4\text{T}_{2g} \rightarrow {}^4\text{A}_2$ transitions, as shown in Fig. 4. Hence in addition to the line emission due to ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions, broad band emission occurs when the temperature rises, and the ${}^4\text{T}_{2g}$ states are populated by thermally induced transitions from the ${}^2\text{E}_g$ levels (black dotted arrow). The positions of the main excitation bands and emission peaks of Cr^{3+} and Mn^{4+} observed at low temperature are listed in Table 2. The subsequent studies of the luminescence of $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$, Mn^{4+} have revealed the influence of temperature.

Initially, our study focussed on temperature-induced variations of the narrow band emissions of Mn^{4+} and Cr^{3+} caused by the ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions in the Li_2SnO_3 . Fig. 5(a) shows that with rising temperature the intensity of the emission lines experiences a gradual reduction with increasing temperature. High-resolution low-temperature photoluminescence measurements revealed that the zero-phonon (R_1) line of Cr^{3+} appears as two closely spaced lines which merge into a single line above

100 K while the R_2 line of Cr^{3+} remains unsplit even at the lowest temperatures. In the case of Mn^{4+} a pair of R_1 and R_2 lines is clearly visible in low-temperature spectra as illustrated in Fig. 5(b). This dual set of R-lines for both Cr^{3+} and Mn^{4+} centers implies the existence of two distinct types of these centers, originating from the substitution of TM ions for two different sites occupied by Sn^{4+} cations in the host lattice. It is pertinent to remark that incorporation of TM ions at different crystallographic sites is a common feature observed in complex oxides.^{26–28}

The observed temperature dependencies offer insight into the dynamics governing the population of excited states within the emission centres under consideration. To attain a more comprehensive understanding of this behaviour, we examined the normalized intensity of various emissions, presented as a function of temperature (see Fig. 6). As it is seen, the ${}^2\text{E} \rightarrow {}^4\text{A}_2$ emission of Cr^{3+} and Mn^{4+} is significantly affected by thermal quenching. Our finding suggests that the measured temperature dependence cannot be adequately modelled by a canonical Mott-Seitz type expression which is typically employed to describe thermal quenching as a single step deactivation process.^{29,30}

Aiming to address this behaviour comprehensively, we adopted an approach previously validated in ref. 31 using an equation designed to accommodate the presence of two distinct pathways for thermal deactivation:

$$I(T) = \frac{I_0}{1 + C_1 \exp\left(-\frac{E_1}{kT}\right) + C_2 \exp\left(-\frac{E_2}{kT}\right)}, \quad (2)$$

In this equation, I_0 is the total emission intensity at zero temperature, C_1 and C_2 are the transition rate constants, E_1 and E_2 are the activation energies for the non-radiative quenching, k is the Boltzmann constant. Using this equation, we achieved a very good agreement of the theoretical curve (the solid red line in Fig. 6) with the experimental data. The parameters of the fit are summarized in Table 3.

A prominent feature of the luminescence in Li_2SnO_3 is a broad band emission associated with the ${}^4\text{T}_{2g} \rightarrow {}^4\text{A}_2$ transitions of Cr^{3+} which becomes prominent with increasing temperature, peaking at *ca.* 225 K as displayed in Fig. 7. Subsequently, it undergoes a gradual decline, disappearing above 500 K. This type of temperature dependence, referred to as negative thermal quenching, has been observed in the luminescence of some materials,^{32,33} including phosphors doped with TM ions.³⁴ The phenomenon is explained by considering two main

Table 2 Position of Mn^{4+} and Cr^{3+} emission and excitation peaks in $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$, Mn^{4+}

Ion, (position)	$\bar{E} \rightarrow {}^4\text{A}_2$ (R_1 -line), nm	$2\bar{A} \rightarrow {}^4\text{A}_2$ (R_2 -line), nm	$\text{R}_1 - \text{R}_2$ gap, meV	${}^4\text{A}_2 \rightarrow {}^4\text{T}_{2g}$, nm	${}^4\text{A}_2 \rightarrow {}^4\text{T}_{1g}$, nm
Mn^{4+} (i)	655.9	654.4	4.0	473	(Not detected) ^a
Mn^{4+} (ii)	656.4	655.6	2.4		
Cr^{3+} (i)	699.0	698.5	1.7	617	440
Cr^{3+} (ii)	699.1	698.5	1.6		

^a The high energy excitation band ${}^4\text{A}_2 \rightarrow {}^4\text{T}_{1g}$ of Mn^{4+} is not resolved due to overlap with the excitation band, resulting from the charge-transfer transitions $\text{O}^{2-} \rightarrow \text{Mn}^{4+}$.



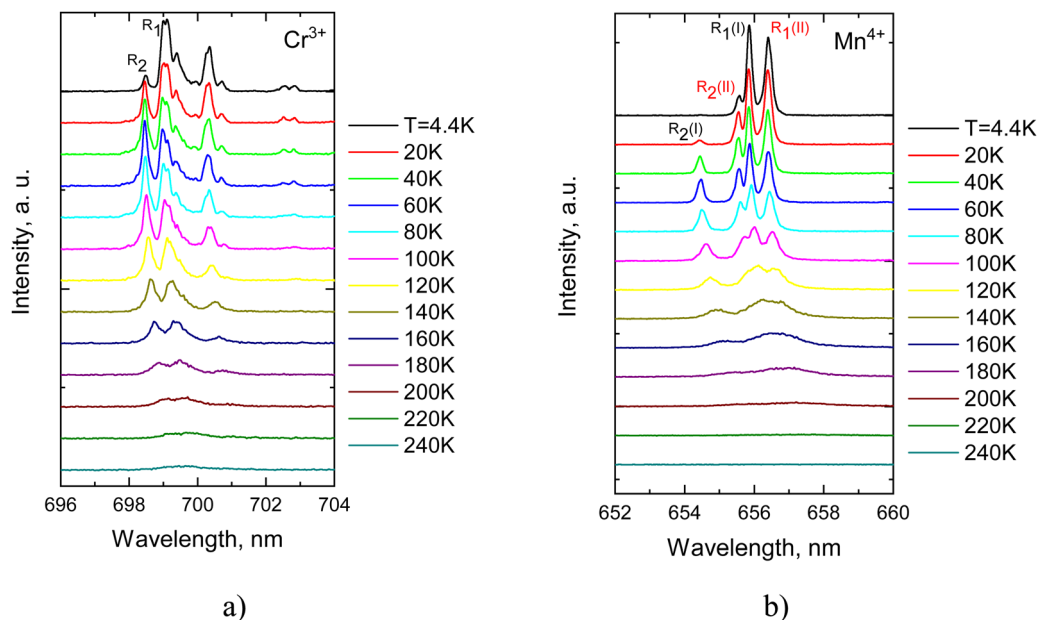


Fig. 5 Temperature evolution of ZPL emission (${}^2E \rightarrow {}^4A_2$) for Cr^{3+} (a) and Mn^{4+} (b) in $Li_2SnO_3-Cr^{3+}$, Mn^{4+} .

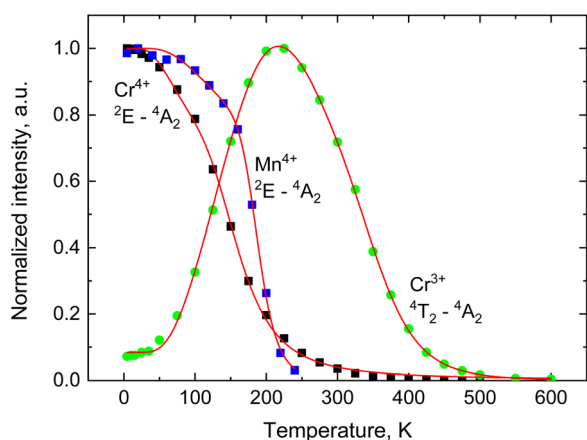


Fig. 6 Normalized intensity of the narrow-line (${}^2E \rightarrow {}^4A_2$) emissions of Mn^{4+} (blue) and Cr^{3+} (black) and broadband (${}^4T_2 \rightarrow {}^4A_2$) emission of Cr^{3+} (green) with temperature. Red lines show the fitting of experimental results by eqn (2) and (3).

Table 3 Parameters of the fit of luminescence intensity as function of temperature, using eqn (2) and (3)

Parameter	Mn^{4+} (${}^2E \rightarrow {}^4A_2$)	Cr^{3+} (${}^2E \rightarrow {}^4A_2$)	Cr^{3+} (${}^4T_{2g} \rightarrow {}^4A_2$)
I_0	1	1	0.084 ± 0.004
A_1	—	—	53.5 ± 3.7
E'_1 , meV	—	—	24.9 ± 0.8
C_1	1.6 ± 0.6	1.5 ± 0.4	$1.10 \pm 0.28 \times 10^2$
E_1 , meV	25.9 ± 4.2	14.8 ± 1.7	113 ± 7
C_2	$2.8 \pm 0.3 \times 10^6$	$8.5 \pm 2.1 \times 10^2$	$5.2 \pm 0.5 \times 10^6$
E_2 , meV	239 ± 18	93 ± 4	453 ± 31
R^2	0.999	0.999	0.999

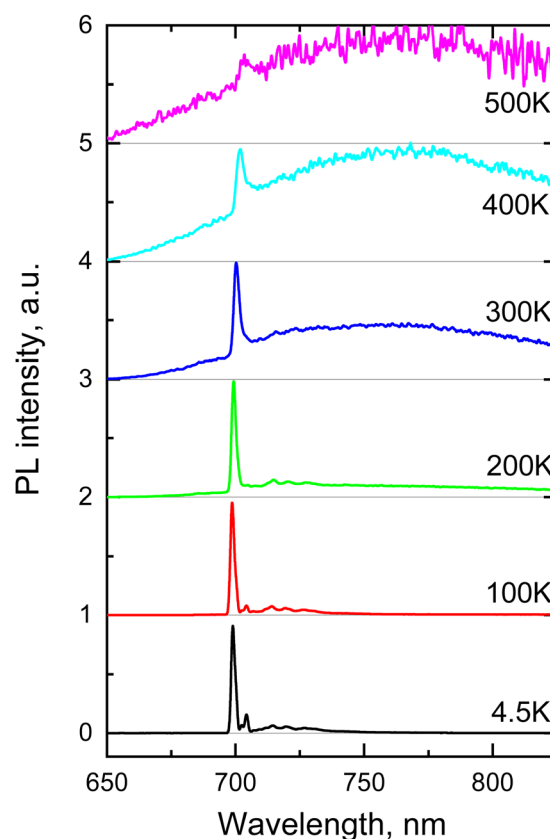


Fig. 7 Temperature evolution of the PL spectrum of Cr^{3+} ions in Li_2SnO_3 excited at 610 nm.

processes that govern the population of the emitting state (i) thermally activated population of the emitting centres that lead

to an increase of the luminescence and (ii) the quenching of the emission intensity due to the non-radiative decay of emission centres. In the framework of the model developed by Shibata³⁵



the observed temperature behaviour of broadband emission can be readily understood, considering that the ${}^4T_{2g}$ state is being populated through the thermally activated crossover transition from the metastable 2E levels of Cr^{3+} as illustrated in Fig. 4. This process is responsible for the emergence of this band with heating with the decrease of the emission intensity occurring above 225 K, the result of thermal quenching. It should be noted that the increase in intensity of this band coincides with a simultaneous decrease in the intensity of the ${}^2E \rightarrow {}^4A_2$ emission intensity of Cr^{3+} , also evident in Fig. 7. To account for this activation process within the model, an additional term is introduced in the numerator of eqn (2) which leads to the following expression for the temperature dependence of the emission intensity:³⁵

$$I(T) = I_0 \frac{1 + A_1 \exp\left(-\frac{E'_1}{kT}\right)}{1 + C_1 \exp\left(-\frac{E_1}{kT}\right) + C_2 \exp\left(-\frac{E_2}{kT}\right)} \quad (3)$$

In this formula, the additional parameters A_1 and E'_1 are the transition rate constant and the activation energy necessary to promote the charged electrons from the metastable to the emission state respectively. Consequently, the expression in the numerator is responsible for the rise of emission due to the thermally activated population of the emitting transition ${}^4T_{2g}$ states. Conversely, the denominator of the equation encompasses processes related to thermally activated non-radiative quenching of the emitting state. The measured temperature dependence of the integrated luminescence intensity of the broad band emission of Cr^{3+} was fitted using this equation over the entire temperature range confirming validity of the model used (see Fig. 6). The best fit was achieved using parameters collated in Table 3. The value for energy E'_1 obtained from the fit ($E'_1 = 24.9 \pm 0.8$ meV) corresponds to the energy barrier of the thermal activation of ${}^2E \rightarrow {}^4T_{2g}$ transitions in the Cr^{3+} ion.

Finally, the photoluminescence quantum yield of Cr^{3+} emission in Li_2SnO_3 at room temperature was determined to be $4.5 \pm 0.4\%$. Notably the room-temperature intensity is approximately 0.4 in comparison to that at 4.2 K leading us to deduce

an approximate quantum efficiency of 11% at lower temperature that is deemed satisfactory for thermometry measurements.

Temperature-induced shift and intensity ratio of R-lines

Next, we analyze the temperature-induced changes in the spectra of the spin-forbidden ${}^2E \rightarrow {}^4A_2$ transitions as illustrated in Fig. 5, where the changes in the narrow emission line's shape or position are evident. These changes primarily originate from the change in the population of emitting states \bar{E} and $2\bar{A}$ and from their interaction with lattice vibrations, resulting in a noticeable variation of the intensity ratio of the R-lines and shifts in their position. Therefore, these two spectroscopic characteristics form the basis for two modes of operation which are frequently utilised in non-contact luminescence measurements of temperature. The temperature dependencies of the intensity ratio ($F = I_{R_2}/I_{R_1}$) for Cr^{3+} and Mn^{4+} lines in Li_2SnO_3 are displayed in Fig. 8, and the variations of peak positions of the R-lines with temperature are shown in Fig. 9.

It is important to note that the presence of two slightly different types of emission centres adds complexity to the interpretation of spectroscopic data. The first issue we encountered was identification of the R-lines of Cr^{3+} . The R_1 lines attributed to $Cr(I)$ and $Cr(II)$ centres are distinguishable only below 100 K, as can be seen in Fig. 5, while the R_2 lines are not resolved at all. Therefore, we derived only one temperature dependence of the intensity ratio for the $Cr(I)$ centre displayed in Fig. 6(a). This dependence was fitted using Boltzmann statistics, which describes the population variation of two emitting levels with temperature:

$$F(T) = A \exp\left(-\frac{D}{kT}\right) + B \quad (4)$$

In this equation, A is a constant, D denotes the energy difference between the two emitting levels, k stands for the Boltzmann constant, T is absolute temperature and B accounts for an offset. The fitting resulted in very good agreement with the experimental data as illustrated in Fig. 8(a). It yielded an energy gap value of $D = 1.9$ meV which aligns well with the

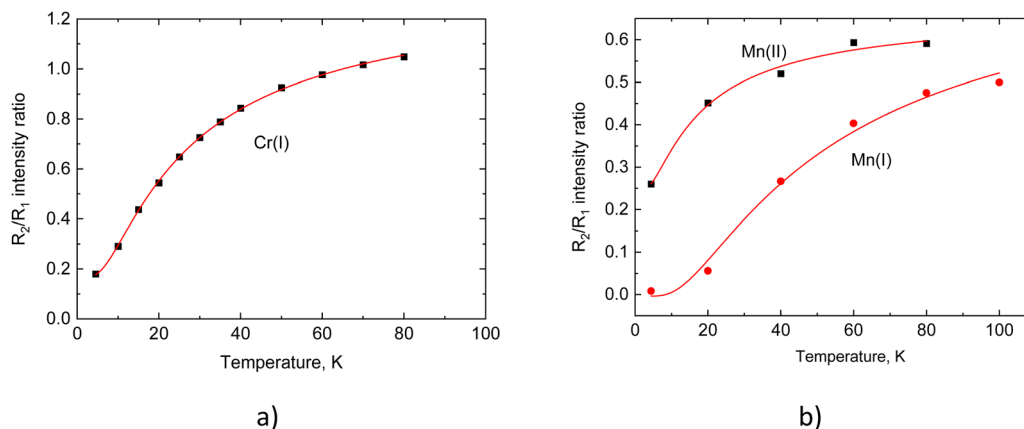


Fig. 8 The intensity ratio (I_{R_2}/I_{R_1}) as a function of temperature for Cr^{3+} (a) and Mn^{4+} centers (b) in Li_2SnO_3 . The red lines display the best fitting of experimental data (dots) to eqn (4) using the value of the energy gap D as shown in Table 4.



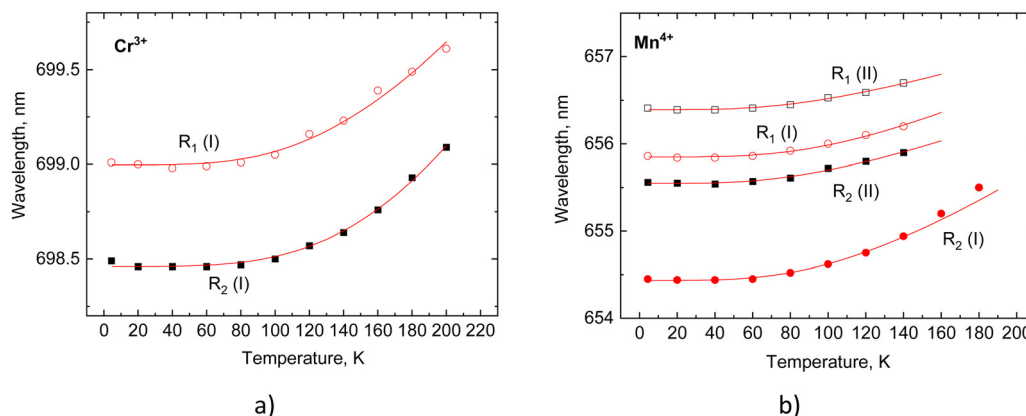


Fig. 9 Variation of the position of R-lines with temperature observed for different emission centers of Cr^{3+} (a) and Mn^{4+} (b) in Li_2SnO_3 . The red lines show the best fit of experimental results (dots) to eqn (5) using the parameters presented in Table 4.

energy difference between the R_1 and R_2 lines obtained from the spectroscopic data.

The second complication arose in assigning two pairs of R-lines to the appropriate emission centres of Mn^{4+} , namely $\text{Mn}(\text{I})$ and $\text{Mn}(\text{II})$. Fortunately, at low temperatures all the individual lines are fully resolved allowing us to apply eqn (4) for verification of their pairing. The best fit was achieved using the values of energy gaps shown in Table 4 which correlates with the results obtained from the spectroscopic measurements (refer to Table 2). This finding also affirms the suggested assignment of the lines to the specific emission centres of Mn^{4+} . It is worth noting that an alternative pairing of R-lines results in values of energy gaps that significantly deviate from the experimentally determined ones.

Following this we examined the temperature-induced changes in the spectral positions of R-lines measured in $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$, Mn^{4+} (see Fig. 9) using the model developed in ref. 36 In the framework of this model the observed shift of the lines, denoted as $\Delta\nu$, originates from the electron-phonon interaction between the excited states of impurity ions and the lattice vibrations of the host material. This phenomenon can be quantified by the formula:

$$\Delta\nu(T) = \alpha \left(\frac{T}{T_D} \right)^4 \int_0^{T_D/T} \frac{x^3}{\exp(x) - 1} dx. \quad (5)$$

Here α represents a coupling coefficient for the electron-phonon interactions and T_D stands for the Debye temperature of the material. We performed a correlated fit of the observed temperature dependences of R-lines, enabling us to determine the optimal values of parameter α for each line as well as the single value for Debye temperature T_D . The fitting procedure

yielded very good agreement with the measured result and the resulting fitting parameters are summarised in Table 4.

These findings allow us to evaluate the potential use of the spectroscopic characteristics of $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$, Mn^{4+} for temperature monitoring. Upon inspecting the two temperature dependences displayed in Fig. 8 and 9 a noteworthy shortcoming become apparent: both methods of temperature sensing, whether based on intensity ratio or R-line shift, are effective within a relatively narrow temperature range. The operational range of the intensity ratio method is limited to 80 K, while discernible changes in the position of the Cr^{3+} peak can be detected within the temperature range 100–200 K. This inherent limitation of these two methods has already been noticed in previous studies.¹⁴ However, with $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$, Mn^{4+} this constraint is more pronounced, limiting the application of two method based on spectroscopic data in non-contact temperature measurements.

Temperature dependence of the luminescence decay time

The change of decay time constant of the R-lines is yet another feature of emission of TM ions that is regularly applied for temperature monitoring.^{26,37–39} To verify the merit of these characteristics we measured the variation of luminescence decay time constants of the R-lines in Li_2SnO_3 . Fig. 10 shows the temperature dependence of decay time constants for ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions of Cr^{3+} and Mn^{4+} .

Both measured dependences $\tau(t)$ exhibit similar qualitative behaviour. Starting at the lowest temperature, the decay time constant initially increases but after reaching a maximum begins to decrease. The main difference lies in the rate of this reduction: it occurs swiftly in case of Cr^{3+} , while in case of Mn^{4+} one can see a levelled-off part in the $\tau(t)$ graphs followed by a rapid decrease in the decay time constant above 170 K. The observed decrease of the decay time constant at higher temperature is commonly observed in luminescence materials.⁴⁰ It has the same origin as the temperature quenching, which is caused by an increase of the probability for non-radiative de-excitation of the emitting level of TM ions.^{30,41,42} The rise of the decay time constant with heating at low temperature is an interesting feature that has been previously documented in a few systems doped with Cr^{3+} .^{38,43} More recently we observed this

Table 4 Fitting parameters derived from the temperature dependence of the intensity ratio and shift of R-lines in $\text{Li}_2\text{SnO}_3:\text{Cr}^{3+}$, Mn^{4+} using eqn (4) and (5), respectively

Emission center	D , meV	α_1 , cm^{-1}	α_2 , cm^{-1}	T_D , K
Cr(I)	1.9 ± 0.1	−705	−678	738
Mn(I)	3.9 ± 0.4	−437	−596	510
Mn(II)	1.2 ± 0.3	−215	−257	413



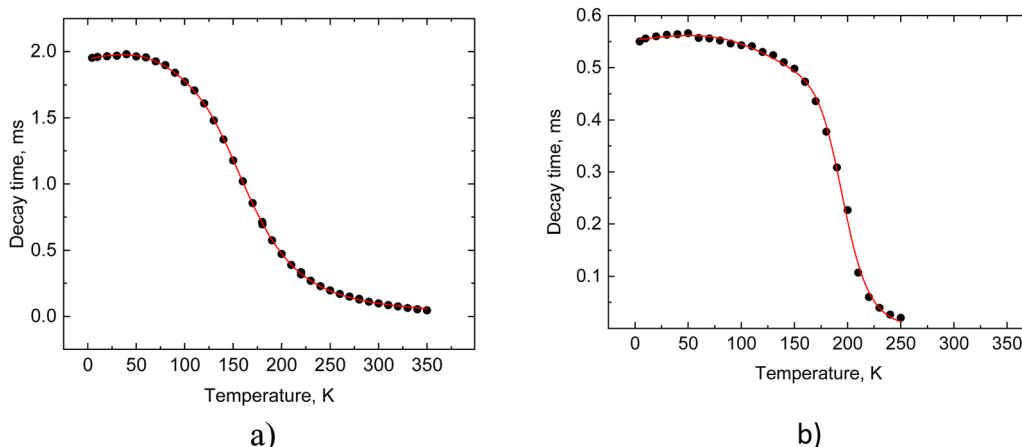


Fig. 10 Temperature dependence of the luminescence decay time constant of Cr^{3+} (a) and Mn^{4+} (b) R-lines in $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} . The solid lines show the best fit of eqn (6) to the experimental results (dots) using the parameters summarized in Table 5.

phenomenon for both ions in Al_2O_3 co-doped with Cr^{3+} and Mn^{4+} .¹⁴ This behaviour is explained by considering different radiative transition probabilities from the \bar{E} and $2\bar{A}$ levels, which together constitute the emitting ${}^2\text{E}$ state. The likelihood of radiative decay from the upper level $2\bar{A}$ is lower compared to that for \bar{E} , *i.e.* $1/\tau_2 < 1/\tau_1$. At very low temperature the upper level remains unpopulated, and consequently, the single R_1 line observed in the emission is predominantly a result of radiative transition from the low-lying level \bar{E} which has a shortened decay time τ_1 . As the temperature increases the upper level gradually becomes populated, as indicated by the emergence of the R_2 line, and it starts to contribute to the emission process. This leads to the gradual increase of the measured decay time constant of the R-emission with heating.

To analyse the relaxation dynamics of ${}^2\text{E}$ emitting states in $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} , we applied a model developed in ref. 38 that provides a comprehensive interpretation of the observed behavior of the decay time constant of TM ions over a wide temperature range. The model offers a highly accurate quantitative description of all features of $\tau = f(T)$ characteristic of Cr^{3+} and Mn^{4+} emissions. It takes into consideration the primary processes influencing the dynamics of radiative transitions, which encompass thermalisation between the \bar{E} and $2\bar{A}$ levels, phonon-assisted relaxation, and depopulation of the levels due to thermally induced transitions from ${}^2\text{E}$ to an upper ${}^4\text{T}_2$ state. It is pertinent to remark that the upper state may subsequently play a different role. For instance, in case of Cr^{3+} it actively participates in luminescence giving rise to broadband emission, whereas in the case of Mn^{4+} it undergoes non-radiative decay through the crossover process. Regardless of these nuances the dependence of the decay time constant of the ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions in Li_2SnO_3 on temperature is described by the following relation:

$$\tau(T) = \frac{1 + \exp\left(-\frac{D}{kT}\right) + 6 \exp\left(-\frac{\Delta E}{kT}\right)}{\frac{1}{\tau_1} \coth\left(\frac{E_p}{2kT}\right) + \frac{1}{\tau_2} \coth\left(\frac{E_p}{2kT}\right) \exp\left(-\frac{D}{2kT}\right) + \frac{6}{\tau_3} \exp\left(-\frac{\Delta E}{kT}\right)}, \quad (6)$$

Table 5 Fitting parameters obtained from the temperature dependence of the luminescence decay time constants of ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions of Cr^{3+} and Mn^{4+} in $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+}

Parameter	Cr^{3+}	Mn^{4+}
τ_1 , ms	1.95 ± 0.01	0.55 ± 0.01
τ_2 , ms	2.03 ± 0.01	0.57 ± 0.01
E_p , meV	25.4 ± 0.2	35.3 ± 0.1
D^a , meV	1.7	3.2
τ_3 , μs	5.8 ± 0.2	$5.5 \pm 0.5 \times 10^{-5}$
ΔE , meV	103.8 ± 0.7	292 ± 16
R^2	0.999	0.998

^a The value of D is fixed to be equal to the average energy splitting of the ${}^2\text{E}$ level.

where $1/\tau_i$ ($i = 1, 2$ and 3) represents the radiative decay rates of the \bar{E} , $2\bar{A}$, and ${}^4\text{T}_2$ states respectively. ΔE is the energy difference between the ${}^2\text{E}$ and the upper state, E_p stands for “effective energy” of the phonons responsible for the exchange with the sidebands.

This equation has been used to model the temperature dependence of the luminescence decay time constants of R-lines of both Cr^{3+} and Mn^{4+} in $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} . The curves displayed in Fig. 10 exhibit an excellent agreement with the experimental results, as substantiated by a high correlation coefficient (> 0.998). The fitting parameters are summarized in Table 5.

Upon examining the fitting parameters, it becomes evident that for the ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions of both Cr^{3+} and Mn^{4+} the decay time constants of the lower level (τ_1) is shorter than that of the upper level (τ_2), which is in line with the reasoning proposed here for the interpretation of the observed behaviour of the luminescence decay time constant at very low temperatures. It is worth noting that the values of activation energies ΔE obtained here are similar to those derived from fitting the temperature dependence of the emission intensity of R-lines. This correspondence is expected given that temperature changes of both intensity and radiative decay are controlled by the same mechanism of non-radiative quenching.



Thermometric performance

The observed substantial changes in the decay time constant of R-lines of Cr^{3+} and Mn^{4+} in Li_2SnO_4 with changing temperature serve as strong indicators that this property can be readily utilized for temperature monitoring. The assessment of efficiency of a measured quantity Q for temperature sensing is done using the quality indicators such as relative sensitivity (S_r) and the temperature uncertainty or resolution (δT) determined using the following equations.^{44,45}

$$S_r = \frac{1}{Q} \left| \frac{dQ}{dT} \right| \times 100\% \quad (7)$$

$$\delta T = \delta Q \left| \frac{dQ}{dT} \right|^{-1} \quad (8)$$

where $|dQ/dT|$ represents the responsivity of the sensor and δQ stands for uncertainty of the measured quantity.

Fig. 11 shows the calculated quality indicator parameters for the thermometer based on the measurements of the decay time constants in $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} along with pertinent data for the reference sample $\text{Ga}_2\text{O}_3\text{-Cr}^{3+}$.³⁸ Upon close examination of the plots in Fig. 11 it becomes evident that the efficiency of temperature sensing using the Cr^{3+} -emission of Li_2SnO_4 is very comparable to that of $\text{Ga}_2\text{O}_3\text{-Cr}^{3+}$. The difference lies in a slight shift of the peak sensitivity from 160 to 190 K and an increase of the relative sensitivity from 1.7 to 2.0%/K. This leads to modest

enhancement of the best achievable temperature uncertainty of $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$ compared to the reference $\text{Ga}_2\text{O}_3\text{-Cr}^{3+}$, from 0.3 to 0.25 K. Assuming an uncertainty ± 1 K as an upper limit for practical application of a temperature sensor, it is evident that this material exhibits resolution ± 1 K or better over a broad temperature range (100–350 K) surpassing that of $\text{Ga}_2\text{O}_3\text{-Cr}^{3+}$.

Finally, the maximum sensitivity of temperature sensing using Mn^{4+} emission of Li_2SnO_3 is nearly three times better, resulting in an impressive resolution $\delta T = 0.08$ K at 220 K. While this performance competes with the best uncertainties achieved by non-contact luminescence decay time sensors (refer to Table 6), it is effective merely within a narrow range (180–250 K).

Summary

Due to their high sensitivity to temperature changes, oxides doped with TM ions find extensive use in non-contact luminescence thermometry. In most cases, temperature sensing relies on monitoring the luminescence properties of a single TM ion. However, it has been demonstrated that employing two TM ions can extend the sensor sensitivity to a wider temperature range and add redundancy. Inspired by this concept, our work focuses on exploring the potential of Li_2SnO_3 co-doped with Cr^{3+} and Mn^{4+} as a non-contact temperature sensor.

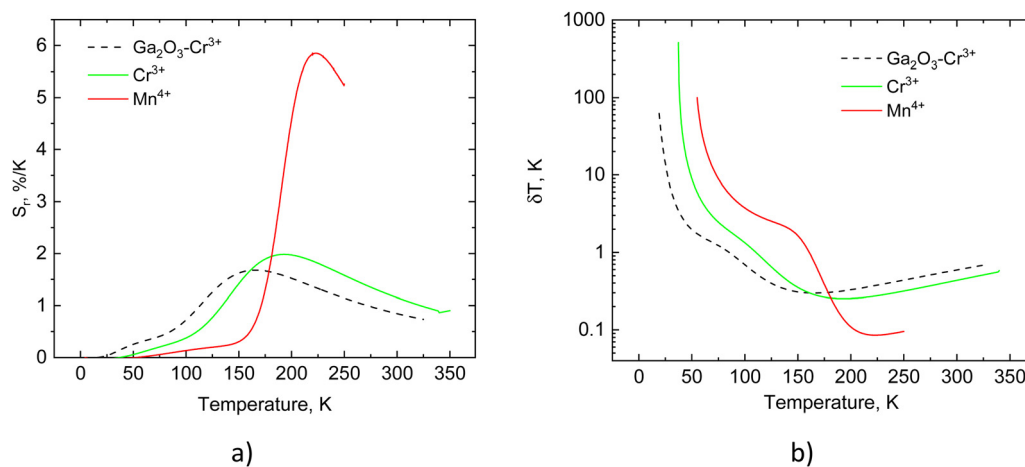


Fig. 11 Relative sensitivity S_r (a) and uncertainty δT of temperature measurements (b) using the decay time constant of ${}^2E \rightarrow {}^4A_2$ transitions of Cr^{3+} and Mn^{4+} in $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} . The data for $\text{Ga}_2\text{O}_3\text{-Cr}^{3+}$ are shown for comparison.

Table 6 Thermometric characteristics of Cr^{3+} and Mn^{4+} doped oxides

Material	Temperature	Relative sensitivity, %/K	Temperature uncertainty, K	Ref.
$\text{Ga}_2\text{O}_3\text{-Cr}^{3+}$	165	1.7	0.3	38
$\text{Mg}_2\text{SiO}_4\text{-Cr}^{3+}$	240	0.92	0.2	46
$\text{ZnGa}_2\text{O}_4\text{-Cr}^{3+}$	200	1.9	<2	47
$\text{MgTiO}_4\text{-Mn}^{4+}$	277	4.1	0.025	48
$\text{Li}_2\text{TiO}_3\text{-Mn}^{4+}$	332	3.2	0.031	49
$\text{LaTiSbO}_6\text{-Mn}^{4+}$	298	3.0	0.05	50
$\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$	190	2.0	0.25	This work
$\text{Li}_2\text{SnO}_3\text{-Mn}^{4+}$	220	5.8	0.08	This work



To comprehend the relationship between the structure and luminescence properties of TM ions in this compound, we conducted examinations using X-ray diffraction, electron paramagnetic resonance, and luminescence techniques. Our structural studies revealed two types of distinct $[\text{SnO}_6]$ octahedral centres in Li_2SnO_3 , both suitable for incorporating TM ions. This finding was further confirmed by EPR and luminescence spectroscopy. Notably, high-resolution, low-temperature photoluminescence measurements distinctly revealed two pairs of R-lines attributed to the ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions in Mn^{4+} in Li_2SnO_3 . The energy gap between the R-lines of Cr^{3+} remains distinguishable but is significantly smaller, while the separation of R-lines resulting from two different Cr^{3+} centres is very small. All of this indicates a reduced strength of the local crystal field compared to that experienced by Mn^{4+} ions.

To evaluate the material suitability for non-contact luminescence thermometry, we investigated the temperature behaviour of the luminescence spectra and decay time constant of Li_2SnO_3 co-doped with Cr^{3+} and Mn^{4+} . The results were analysed within the framework of relevant theoretical models, which explain the observed temperature dependences arising from various mechanisms affecting the dynamics of excited states due to thermalization, electron-phonon interaction, non-radiative decay, and thermally-activated depopulation. Following this analysis, we found that spectroscopic techniques for temperature monitoring based on measurements of the intensity ratio of R-lines or their spectral shift in $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} are effective only within a relatively narrow temperature range, limiting their practical application. In contrast, we discovered that thermometry based on measurements of the decay time constant of the ${}^2\text{E} \rightarrow {}^4\text{A}_2$ transitions of TM ions in Li_2SnO_3 shows great promise, as this luminescence parameter exhibits high sensitivity to temperature changes.

The relative sensitivity of Cr^{3+} emission, equal to 2.0%/K at 190 K, is comparable to that demonstrated by $\text{Ga}_2\text{O}_3\text{-Cr}^{3+}$ taken as reference. This translates to an expected temperature resolution of measurements better than ± 1 K over a broad temperature range from 100 to 350 K. The emission of Mn^{4+} exhibits even higher sensitivity at 220 K, with a value of 5.8%/K. However, due to steep thermal quenching, practical temperature measurements are only possible within a narrow range of temperatures. Nevertheless, this emission may be very useful for cross-verifying results of temperature measurements obtained from the Cr^{3+} emitter. This added feature enhances the potential of $\text{Li}_2\text{SnO}_3\text{-Cr}^{3+}$, Mn^{4+} as a non-contact luminescence sensor for temperature.

Conflicts of interest

There are no conflicts to declare.

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